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Fault detection system, storage device and server

Abstract

Disclosed in the present application is a fault detection system, a storage device and a server. The fault detection system includes a supercapacitor circuit, a switch module and a controller module, the supercapacitor circuit is configured to obtain electrical energy from the voltage conversion circuit and store the electrical energy, the switch module is configured to conduct or disconnect a connection between the supercapacitor circuit and the voltage output terminal, the controller module is configured to turn on the switch module, obtain state information of the storage device, and control a reminder circuit to output reminder information based on the state information when the first voltage is less than a voltage threshold.

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Background/Summary

FIELD

(1) The present disclosure relates to the technical field of servers, and specifically to a fault detection system, a storage device, and a server.

BACKGROUND

(2) Baseboard management controllers (BMCs) or microcontroller units (MCUs) are often used in servers, just a bunch of flash (JBOF) or just a bunch of disks (JBOD) to record error messages, allowing maintenance personnel to use the error messages to find out where electronic circuits are damaged and information about hard disk damage. In the event of an unexplained shutdown and the power supply unit (PSU) is unable to supply power, it is not possible to directly obtain information such as the location of the failure to quickly replace the damaged hard disk device, which will make it more difficult to efficiently maintain the data center. Even if the system uses a backup power supply, complex hardware and software structures need to be configured, and

maintenance personnel cannot quickly tell where electronic circuits have been damaged and where the hard disk has been damaged.

(3) Therefore, improvement is desired.

Description

BRIEF DESCRIPTION OF THE DRAWINGS

- (1) FIG. **1** is a block diagram of a fault detection system according to an embodiment of the present disclosure.
- (2) FIG. **2** is another block diagram of the fault detection system according to an embodiment of the present disclosure.
- (3) FIG. **3** is a partial circuit diagram of a detection circuit according to an embodiment of the present disclosure.
- (4) FIG. **4** is a partial circuit diagram of the detection circuit according to an embodiment of the present disclosure.
- (5) FIG. **5** is a partial circuit diagram of a charge circuit according to an embodiment of the present disclosure.
- (6) FIG. **6** is a partial circuit diagram of a switch circuit according to an embodiment of the present disclosure.
- (7) FIG. **7** is a block diagram of a storage device according to an embodiment of the present disclosure.
- (8) FIG. **8** is a block diagram of a server according to an embodiment of the present disclosure. DETAILED DESCRIPTION
- (9) In the embodiments of the present application, the terms "exemplary" or "for example" are used to denote examples, illustrations, or descriptions, any embodiment or design solution described as "exemplary" or "for example" in the embodiments of the present application should not be construed as being preferred or advantageous over other embodiments or design solutions. The use of the terms "exemplary" or "for example" is intended to present the concepts in a concrete manner.
- (10) When a component is referred to as "electrically connected" to another component, it can be directly connected to another component or there can be a centered component present. When a component is "electrically connected" to another component, it can be a contact connection, for example, it can be a wire connection, or it can be a non-contact connection, for example, it can be a non-contact coupling method.
- (11) Baseboard management controllers (BMCs) or microcontroller units (MCUs) are often used in servers, just a bunch of flash (JBOF) or just a bunch of disks (JBOD) to record error messages, allowing maintenance personnel to use the error messages to find out where electronic circuits are damaged and information about hard disk damage. In the event of an unexplained shutdown and the power supply unit (PSU) is unable to supply power, it is not possible to directly obtain information such as the location of the failure to quickly replace the damaged hard disk device, which will make it more difficult to efficiently maintain the data center. Even if the system uses a backup power supply, complex hardware and software structures need to be configured, and maintenance personnel cannot quickly tell where electronic circuits have been damaged and where the hard disk has been damaged.
- (12) In order to solve the above problems, the present application provides a fault detection system, a storage device and a server to quickly locate a faulty storage unit when the PSU is unable to supply power.
- (13) Embodiments of the present disclosure are further described below in conjunction with the accompanying drawings.

- (14) FIG. **1** illustrates a fault detection system **10** in accordance with an embodiment of the present disclosure.
- (15) The fault detection system **10** is applied to a storage device **20**. The fault detection system **10** is used to quickly identify memory that has failed when the storage device **20** is powered down. The storage device **20** can be any electronic device provided with a memory. The memory may be replaceable storage. For example, in some embodiments, the storage device **20** may be a redundant arrays of independent disks (RAID) storage device, a JBOD storage device, a JBOF storage device, or other server. The present application does not limit the specific type of the storage device **20**. (16) The storage device **20** includes a voltage conversion circuit **210** and a voltage output terminal **220**. The voltage conversion circuit **210** is used to convert a first supply voltage of an external power (not shown in figures) and output a second supply voltage to the voltage output terminal **220**. For example, the voltage conversion circuit **210** includes an AC/DC conversion circuit, the voltage conversion circuit **210** can receive a 220V alternating current (AC) voltage or a 110V AC voltage from the external power, and convert the 220V voltage or the 110V voltage into a direct current (DC) voltage and output the DC voltage through the voltage output terminal 220. In one embodiment, the voltage conversion circuit **210** can be a PSU. The voltage output terminal **220** is used to output a first voltage to supply power to the fault detection system **10**. The voltage output terminal **220** is connected to each power input port of the fault detection system **10**, at least one DC/DC conversion circuit can be installed at the voltage output terminal 220 to convert the DC power output by the voltage conversion circuit **210** into a power supply voltage suitable for the electrical unit, such as 12V, 5V, 3.3V, and other types of DC voltage.
- (17) The fault detection system **10** includes a supercapacitor circuit **110**, a switch module **120**, a detection circuit **130**, a reminder circuit **140**, and a controller **150**.
- (18) In the embodiment, a first end of the supercapacitor circuit **110** is connected between the voltage conversion circuit **210** and the voltage output terminal **220**, a second end of the supercapacitor circuit **110** is connected to a first end of the switch module **120**. A second end of the switch module **120** is connected between the voltage conversion circuit **210** and the voltage output terminal **220**. A first end of the controller **150** is connected to a third end of the switch module **120**, a second end of the controller **150** is connected to a first end of detection module detection circuit **130**, a second end of the detection circuit **130** is connected to the voltage output terminal **220**, and a third end of the controller **150** is connected to the reminder circuit **140**.
- (19) In the embodiment, the controller **150** is used to control the state of the switch module **120**. For example, the controller **150** can outputs a first control signal to the switch module **120** to turn on the switch module **120**, and the controller **150** can outputs a second control signal to the switch module **120**, to turn off the switch module **120**.
- (20) The supercapacitor circuit **110** is used to obtain electrical energy from the voltage conversion circuit **210** and store the electrical energy, when the switch module is turned on, the switch module conducts the connection between the supercapacitor circuit and the voltage output terminal, when the switch module is turned off, the switch module disconnects the connection between the supercapacitor circuit and the voltage output terminal.
- (21) When the switch module **120** is turned on, the switch module **120** can conduct the connection between the supercapacitor circuit **110** and the voltage output terminal **220**, so that the supercapacitor circuit **110** outputs voltage to the voltage output terminal **220**. When the switch module **120** is turned off, the switch module **120** disconnects the connection between the supercapacitor circuit **110** and the voltage output terminal **220**, so that the voltage of the supercapacitor circuit **110** cannot be output to the voltage output terminal **220**. The switch module **120** includes, but is not limited to, a gate switch, a transistor, a relay, the present application does not limit the specific type of the switch module **120**, only that the switch module **120** can control the conduction or disconnection of the path between the supercapacitor circuit **110** and the voltage output terminal **220**.

- (22) The detection circuit **130** is used to detect the voltage at the voltage output terminal **220**. The detection circuit **130** includes electronic components such as a voltage sensor, an amplifier, a resistor. The present application does not limit the specific circuit structure of the detection circuit **130**, only that the detection circuit **130** can at least accomplish the voltage detection function.
- (23) The reminder circuit **140** is used to output a reminder information. The reminder circuit **140** includes a speaker or a light-emitting diode (LED). The reminder information includes, but is not limited to, the speaker chirping, the LED lights blinking or going out.
- (24) When the voltage of the voltage output terminal **220** is less than a voltage threshold, the controller **150** is used to turn on the switch module **120** and obtain error information of the storage device **20**, and control the reminder circuit **140** to output the reminder information based on the error information. In the embodiment, the controller **150** may be a complex programmable logic device (CPLD). In other embodiments, the controller **150** may be a field programmable logic gate array (FPGA) or a microcontroller unit (MCU).
- (25) The fault detection system **10** illustrated in FIG. **1** operates generally as follows:
- (26) When the voltage conversion circuit **210** is in an operating state, the voltage conversion circuit **210** converts the voltage input from an external power supply and outputs a voltage to the voltage output terminal **220**. The voltage output terminal **220** supplies power to the various power-using units in the fault detection system **10**, for example, the voltage output terminal **220** supplies power to the controller **150** and the reminder circuit **140**. When the controller **150** determines that a first voltage is greater than or equal to the voltage threshold, the controller **150** maintains the state in which the switch module **120** is turned off, and the supercapacitor circuit **110** further obtains the electrical energy output from the voltage conversion circuit **210** for charging.
- (27) When the controller **150** determines that the first voltage is less than the voltage threshold, it indicates that the voltage conversion circuit **210** fails or there is no external power input, and the storage device **20** may be shut down due to the lack of electrical energy to maintain operation. Therefore, the controller **150** turns on the switch module **120** to conduct the connection between the supercapacitor circuit **110** and the voltage output terminal **220**, the supercapacitor circuit **110** may output a voltage to the voltage output terminal **220** through the switch module **120**, and the voltage output terminal **220** may supply power to the fault detection system **10**. Due to the power supply of the supercapacitor circuit **110**, the controller **150** may continue to obtain the state information of the storage device **20** and control the reminder circuit **140** to output reminder information based on the state information. Therefore, the maintenance personnel can directly maintain the storage device **20** without rebooting the storage device **20**.
- (28) Even if the maintenance personnel is not able to repair the storage device **20** in time, the state information of the storage device **20** can be stored by the controller **150** because the controller **150** has acquired the state information of the storage device **20**, in order to repair the storage device **20** by means of the state information saved by the controller **150** when the storage device **20** is repowered.
- (29) The present application can supply power to the fault detection system 10 by replenishing the voltage output terminal 220 through the supercapacitor circuit 110 and the switch module 120 when the voltage conversion circuit 210 fails or when there is no external power supply input to maintain the controller 150 to continue operation. The controller 150 may continue to obtain state information and control the reminder circuit 140 to output the reminder information based on the state information, which in turn allows the maintenance personnel to replace a faulty memory in the storage device 20 or repair the malfunction in the storage device 20 based on the reminder information. Even if the storage device 20 is turned off due to a power failure, the faulty memory in the storage device 20 can be quickly determined, due to the supercapacitor circuit 110 supplies power to the fault detection system 10 through the voltage output terminal 220, and the operation time of the reminder circuit 140 is prolonged as much as possible.
- (30) Referring to FIG. 2, in one embodiment, the supercapacitor circuit 110 includes a

supercapacitor **111** and a charge circuit **112**. The fault detection system **10** further includes an anti-reverse circuit **160**. The anti-reverse circuit **160** is connected between the voltage conversion circuit **210** and the voltage output terminal **220**. A first end of the switch module **120** is connected between the anti-reverse circuit **160** and the voltage output terminal **220**, a second end of the switch module **120** is connected to a first end of the supercapacitor **111**, a second end of the supercapacitor **111** is connected to a first end of the charge circuit **112**, a second end of the charge circuit **112** is connected between the voltage conversion circuit **210** and the anti-reverse circuit **160**.

- (31) The charge circuit **112** is used to convert the second supply voltage output by the voltage conversion circuit **210** into a second voltage, and the charge circuit **112** can output the second voltage to charge the supercapacitor **111**. In some embodiments, the charge circuit **112** may be a DC/DC conversion circuit. The supercapacitor **111** is used to store the electrical energy and output a voltage to the voltage output terminal when the switch module is turned on.
- (32) The supercapacitor **111** is used to store electrical energy and outputs a voltage to the voltage output terminal **220** when the switch module **120** is turned on.
- (33) The anti-reverse circuit **160** is used to prevent the current of the supercapacitor circuit **110** from flowing back into the voltage conversion circuit **210**. The anti-reverse circuit **160** is used to prevent the current of the supercapacitor **111** from flowing back into the voltage conversion circuit **210**. In some embodiments, the anti-reverse circuit **160** includes a diode **D2**. The anode of the diode **D2** is connected between the voltage conversion circuit **210** and the supercapacitor circuit **110**, and the cathode of the diode **D2** is connected between the voltage output terminal **220** and the first end of the switch module **120**. The present application does not limit the specific circuit structure of the anti-reverse circuit **160**, only the anti-reverse circuit **160** is required to achieve the corresponding anti current backflow function.
- (34) In some embodiments, the storage device **20** further includes a storage device controller **230**, a memory module **240**, and a state information memory **250**.
- (35) The storage device controller **230** is connected to the state information memory **250** and the memory module **240**. The state information memory **250** is connected to the controller **150** of the fault detection system **10**. The storage device controller **230** is also connected to the reminder circuit **140** of the fault detection system **10**.
- (36) The storage device controller **230** is the control center of the storage device **20**, and the storage device controller **230** utilizes various interfaces and wiring to connect to various portions of the entire storage device **20**, to call up data and/or program instructions within the memory of the storage device **20**, to perform various functions of the storage device **20**, and/or to process data, so as to provide overall management and control of the storage device **20**. In some embodiments, the storage device controller **230** may be a central processor, microprocessor, microcontroller, or other chip with data processing capabilities. For example, when the storage device **20** is a server, the storage device controller **230** may be a CPU.
- (37) The memory module **240** includes a plurality of memories, and the plurality of memories are replaceable memories.
- (38) The state information memory **250** is used to store state information of the device **20**. The state information includes voltage information, current information. The state information further includes fault information and the address of each memory in the memory module **240**. The state information memory **250** includes electrically erasable programmable read only memory (EEPROM), cache, flash memory (FLASH). The present application does not limit the specific types of the state information memory **250**.
- (39) In the embodiment, the reminder circuit **140** includes a plurality of LEDs. The plurality of LEDs can correspond to the plurality of memories one by one, and the state of each LED is used to indicate the operation state of the corresponding memory. The present application can visually determine the state of each memory in the memory module **240** by the state of the corresponding LEDs. The state of the LED includes a first state and a second state, and when the LED is in the

- first state, it indicates that the corresponding memory has malfunctioned or is not connected to the storage device **20**. When the LED is in the second state, it indicates that the corresponding memory is connected to the storage device **20** and is in a normal operating state. For example, the first state is a blinking state, and the second state is an off state.
- (40) In some embodiments, the fault detection system **10** further includes an expansion circuit **170**, a first end of the expansion circuit **170** is connected to the storage device controller **230**, and a second end of the expansion circuit **170** is connected to the reminder circuit **140**, a third end of the expansion circuit **170** is connected to the controller **150**. The expansion circuit **170** is used to realize the control of the reminder circuit **140** by the controller **150** or the storage device controller **230**.
- (41) The expansion circuit **170** includes a plurality of I2C interfaces and input/output expansion circuits. The controller **150** and the storage device controller **230** both store a corresponding control program for the expansion circuit **170**. When the voltage conversion circuit **210** is operating normally, the storage device controller **230** may control the reminder circuit **140** to output reminder information based on the state information in the state information memory **250**. When the voltage conversion circuit **210** is unable to supply power and switches to the supercapacitor circuit **110** to supply power, the controller **150** may obtain the state information from the state information memory **250** and control the reminder circuit **140** to output reminder information based on the state information.
- (42) In some embodiments, each byte within the preset space in the state information memory **250** corresponds to a set of memory units in the memory module **240**, respectively. Each bit in each byte corresponds to each memory unit in the memory. For example, when the data of the corresponding bit in the memory is 0, it indicates that the memory is in a normal operating state. When the data of the corresponding bit in the memory is 1, it indicates that the memory has malfunctioned or is not connected to storage device **20**.
- (43) Referring to FIG. **3** and FIG. **4**, in some embodiments, the detection circuit **130** includes a sample circuit **131** and a voltage comparison circuit **132**. The sample circuit **131** includes a capacitor C**1**, a capacitor C**2**, a resistor R**1**, a resistor R**2**, a resistor R**3**, and a buffer **1311**. The buffer **1311** includes a power pin VCC, a first input pin **1**A, and a first output pin **1**Y. The sample circuit **131** is used to sample the first voltage V_BAT output by the voltage output terminal **220** and output a sample voltage V_BAT_HS. The power pin VCC of the buffer **1311** is connected to a power supply VCC**1**, the first input pin **1**A of the buffer **1311** receives the first voltage V_BAT through the resistor R**1**, the first input pin **1**A of the buffer **1311** is grounded through the capacitor C**2**, a ground pin GND of the buffer **1311** is grounded, and the first output pin **1**Y of the buffer **1311** outputs the sample voltage V_BAT_HS through the resistor R**3**.
- (44) Referring to FIG. **4**, in some embodiments, the voltage comparison circuit **132** includes capacitors C3-C5, resistors R4-R9, a reference voltage source **1321**, and a voltage amplifier **1322**. (45) The first input terminal IN+ of the voltage amplifier **1322** is connected to the output terminal of the sample circuit **131** through resistors R4-R7 to obtain the sample voltage V_BAT_HS. The second input terminal IN- of the voltage amplifier **1322** is connected to the output terminal OUT of the reference voltage source **1321** to obtain a reference voltage (i.e. the voltage threshold). The ground terminal GND of the reference voltage source **1321** is grounded, the input terminal IN of the reference voltage source **1321** is connected to a power supply VCC2, the input terminal IN of the reference voltage source **1321** is grounded through the capacitor C3, the output terminal OUT of the reference voltage source **1321** is grounded through the capacitor C4, and the output terminal OUT of the reference voltage source **1321** is also connected to the second input terminal IN- of the voltage amplifier **1322** through resistor R9. The ground terminal GND of the voltage amplifier **1322** is connected to a power supply VCC3, and the power pin VCC of the voltage amplifier **1322** is also grounded

through the capacitor C5. The first input terminal IN+ of the voltage amplifier **1322** is connected to the output terminal OUT of the voltage amplifier **1322** through resistor R**8**, and the first input terminal IN+ of the voltage amplifier **1322** is also grounded through the resistor R7 and the resistor **R6**. The first input terminal IN+ of the voltage amplifier **1322** also receives the sample voltage V_BAT_HS through the resistor R7, the resistor R5, and the resistor R4. Therefore, the voltage amplifier **1322** can compare the sample voltage V_BAT_HS with reference voltage. In some embodiments, the first voltage and the sample voltage V_BAT_HS has a preset ratio relationship, and the voltage threshold and reference voltage also have the same preset ratio relationship. Therefore, the present application compares the sample voltage V_BAT_HS with the reference voltage to determine the magnitude between the first voltage V_BAT and the voltage threshold. In some embodiments, when the sample voltage V BAT HS is greater than or equal to the reference voltage, the output terminal EN of the voltage comparison circuit 132 outputs a first level signal to the controller **150**. When the sample voltage V_BAT_HS is less than the reference voltage, the output terminal EN of the voltage comparison circuit **132** outputs a second level signal to the controller **150**. The first level signal may be a high-level signal and the second level signal may be a low-level signal.

- (46) Therefore, the controller **150** receives the second level signal output from the voltage comparison circuit **132** of the detection circuit **130**, determines that the first voltage is less than the voltage threshold, turns on the switch module **120** and obtains the state information of the storage device **20**.
- (47) Referring to FIG. **5**, in some embodiments, the charge circuit **112** includes resistors R**10**-R**14**, capacitors C**5**-C**8**, an inductor L**1**, and a charge chip **1121**. The charge circuit **112** is used to obtain the electrical energy output by the voltage conversion circuit **210** to charge the supercapacitor **111**. The EPAD pin of the charge chip **1121** is grounded, the power good signal pin PGOOD of the charge chip **1121** is connected to the switch module **120** through the resistor R**12**, the VSEL pin of the charge chip **1121** is grounded through the resistor R**14**, the C+ pin of the charge chip **1121** is connected to the C-pin of the charge chip **1121** through the capacitor C**7**, the SHDN pin of the charge chip **1121** is also grounded through the resistor R**13**, and the SHDN pin of the charge chip **1121** is also grounded through the capacitor C**8**, the power pin VIN of the charge chip **1121** is grounded through the capacitor C**6**, and the power pin VIN of the charge chip **1121** is also connected to the power supply VCC**5** through the inductor L**1** and the resistor R**11**. A first end of the capacitor C**5** is grounded, a second end of the capacitor C**5** is connected to a node between the inductor L**1** and the resistor R**11**, and the second end of the capacitor C**5** is also connected to a power supply VCC**4** through the resistor R**10**.
- (48) Referring to FIG. **6**, in some embodiments, the switch module **120** includes a MOS transistor **121**, a fuse R**18**, a resistor R**19**, a capacitor C**9**, a capacitor C**10**, a capacitor C**11**, and a diode D**1**. The supercapacitor **111** includes a capacitor C**12** and a capacitor C**13**.
- (49) A gate of the MOS transistor **121** is connected to the control signal output terminal CPLD_EN of the controller **150** through the resistor R**19**, a source of the MOS transistor **121** is connected to the voltage output terminal V_BATCAP of the voltage conversion circuit **210**, and a drain of the MOS transistor **121** is connected to the supercapacitor **111**. Therefore, the MOS transistor **121** conducts or disconnects the path between the voltage output terminal V_BATCAP and the supercapacitor **111** under the control of the control signal output from the control signal output terminal CPLD_EN. When the MOS transistor **121** conducts under the control of the control signal, the supercapacitor **111** (i.e., the capacitor C**12** and the capacitor C**13**) outputs a voltage to the voltage output terminal V_BATCAP, to supply power to the fault detection system **10** through the voltage output terminal V_BATCAP.
- (50) The gate of the MOS transistor **121** is also grounded through the capacitor C**11**, the source of the MOS transistor **121** is also connected to the cathode of the diode D**1**, the drain of the MOS transistor **121** is connected to the anode of the diode D**1**, the drain of the MOS transistor **121** is also

grounded through the capacitor C10, the drain of the MOS transistor 121 is also grounded through the capacitor C9, the drain of the MOS transistor 121 is also grounded through the fuse R18, the capacitor C12, and the capacitor C13, the two ends of the resistor R16 are respectively connected to the two ends of the capacitor C12, and the two ends of the resistor R17 are respectively connected to the two ends of the capacitor C13.

- (51) The fuse R**18** is disconnected when the current is too high to ensure the safety of the fault detection system **10**.
- (52) In some embodiments, multiple switches are also provided at each power input terminal of the fault detection system **10**, which can be disconnected in a timely manner in case of circuit overcurrent or short circuit, to reduce the impact on the voltage output terminal **220**.
- (53) Referring to FIG. **7**, the present application further provides a storage device **20**. The storage device **20** includes a fault detection system **10** as described above. The storage device **20** is any of JBOD storage devices, JBOF storage devices, or RAID storage devices.
- (54) Referring to FIG. **8**, the present application further provides a server **30**. The **30** includes the voltage conversion circuit **210**, the voltage output terminal **220**, the storage device controller **230**, the memory module **240**, the state information memory **250**, and the fault detection system **10** as described above.
- (55) Those of ordinary skill in the art should realize that the above embodiments are only used to illustrate the present disclosure, but not to limit the present disclosure. As long as they are within the essential spirit of the present disclosure, the above embodiments are appropriately made and changes fall within the scope of protection of the present disclosure.

Claims

- 1. A fault detection system applied to a storage device, the storage device comprising a voltage conversion circuit and a voltage output terminal, the voltage conversion circuit configured to convert a first supply voltage and output a second supply voltage to the voltage output terminal, the voltage output terminal configured to output a first voltage to provide power to the fault detection system, and the fault detection system comprising: a supercapacitor circuit configured to obtain electrical energy from the voltage conversion circuit and store the electrical energy; a switch module configured to conduct or disconnect a connection between the supercapacitor circuit and the voltage output terminal, a controller configured to turn on the switch module, obtain state information of the storage device, and control a reminder circuit to output reminder information based on the state information when the first voltage is less than a voltage threshold.
- 2. The fault detection system of claim 1, wherein the controller is configured to turn off the switch module when the first voltage is greater than or equal to the voltage threshold.
- 3. The fault detection system of claim 2, wherein when the switch module is turned on, the switch module conducts the connection between the supercapacitor circuit and the voltage output terminal, when the switch module is turned off, the switch module disconnects the connection between the supercapacitor circuit and the voltage output terminal.
- 4. The fault detection system of claim 1, wherein the supercapacitor circuit comprises a charge circuit and a supercapacitor, the charge circuit is configured to convert the second supply voltage output by the voltage conversion circuit into a second voltage, and output the second voltage to charge the supercapacitor; the supercapacitor is configured to store the electrical energy and output a voltage to the voltage output terminal when the switch module is turned on.
- 5. The fault detection system of claim 1, wherein the fault detection system further comprises an anti-reverse circuit, and the anti-reverse circuit is configured to prevent a current of the supercapacitor circuit from flowing back into the voltage conversion circuit.
- 6. The fault detection system of claim 5, wherein the anti-reverse circuit comprises a diode, an anode of the diode is connected between the voltage conversion circuit and the supercapacitor

circuit, and a cathode of the diode is connected between the voltage output terminal and the switch module.

- 7. The fault detection system of claim 1, wherein the fault detection system further comprises a detection circuit, the detection circuit is connected between the voltage output terminal and the controller, the controller is configured to detect the first voltage through the detection circuit.
- 8. A storage device comprising: a voltage conversion circuit configured to convert a first supply voltage and output a second supply voltage to a voltage output terminal, the voltage output terminal configured to output a first voltage, a fault detection system comprising: a supercapacitor circuit configured to obtain electrical energy from the voltage conversion circuit and store the electrical energy; a switch module configured to conduct or disconnect a connection between the supercapacitor circuit and the voltage output terminal, a controller configured to turn on the switch module, obtain state information of the storage device, and control a reminder circuit to output reminder information based on the state information when the first voltage is less than a voltage threshold.
- 9. The storage device of claim 8, wherein the controller is configured to turn off the switch module when the first voltage is greater than or equal to the voltage threshold.
- 10. The storage device of claim 9, wherein when the switch module is turned on, the switch module conducts the connection between the supercapacitor circuit and the voltage output terminal, when the switch module is turned off, the switch module disconnects the connection between the supercapacitor circuit and the voltage output terminal.
- 11. The storage device of claim 8, wherein the supercapacitor circuit comprises a charge circuit and a supercapacitor, the charge circuit is configured to convert the second supply voltage output by the voltage conversion circuit into a second voltage, and output the second voltage to charge the supercapacitor; the supercapacitor is configured to store the electrical energy and output a voltage to the voltage output terminal when the switch module is turned on.
- 12. The storage device of claim 8, wherein the fault detection system further comprises an antireverse circuit, and the anti-reverse circuit is configured to prevent a current of the supercapacitor circuit from flowing back into the voltage conversion circuit.
- 13. The storage device of claim 12, wherein the anti-reverse circuit comprises a diode, an anode of the diode is connected between the voltage conversion circuit and the supercapacitor circuit, and a cathode of the diode is connected between the voltage output terminal and the switch module.
- 14. The storage device of claim 8, wherein the fault detection system further comprises a detection circuit, the detection circuit is connected between the voltage output terminal and the controller, the controller is configured to detect the first voltage through the detection circuit.
- 15. A server comprising: a voltage conversion circuit configured to convert a first supply voltage input from an external power source and output a second supply voltage to a voltage output terminal, the voltage output terminal configured to output a first voltage, and a fault detection system comprising: a supercapacitor circuit configured to obtain electrical energy from the voltage conversion circuit and store the electrical energy; a switch module configured to conduct or disconnect a connection between the supercapacitor circuit and the voltage output terminal, a controller configured to turn on the switch module, obtain state information of the storage device, and control a reminder circuit to output reminder information based on the state information when the first voltage is less than a voltage threshold.
- 16. The server of claim 15, wherein the controller is configured to turn off the switch module when the first voltage is greater than or equal to the voltage threshold.
- 17. The server of claim 16, wherein when the switch module is turned on, the switch module conducts the connection between the supercapacitor circuit and the voltage output terminal, when the switch module is turned off, the switch module disconnects the connection between the supercapacitor circuit and the voltage output terminal.
- 18. The server of claim 15, wherein the supercapacitor circuit comprises a charge circuit and a

supercapacitor, the charge circuit is configured to convert the second supply voltage output by the voltage conversion circuit into a second voltage, and output the second voltage to charge the supercapacitor; the supercapacitor is configured to store the electrical energy and output a voltage to the voltage output terminal when the switch module is turned on.

- 19. The server of claim 15, wherein the fault detection system further comprises an anti-reverse circuit, and the anti-reverse circuit is configured to prevent a current of the supercapacitor circuit from flowing back into the voltage conversion circuit.
- 20. The server of claim 19, wherein the anti-reverse circuit comprises a diode, an anode of the diode is connected between the voltage conversion circuit and the supercapacitor circuit, and a cathode of the diode is connected between the voltage output terminal and the switch module.